

isc N-Channel MOSFET Transistor

2SK1938

DESCRIPTION

- Drain Current –I_D=18A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}=500V(Min)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

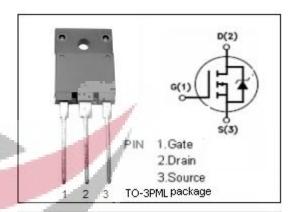
- Switching regulator
- UPS
- General purpose power amplifier

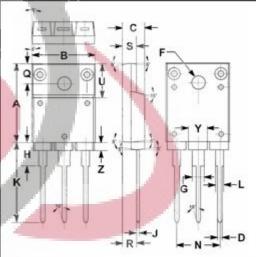
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V ₆₈ =0)	500	V
V _{GS}	Gate-Source Voltage	±30	V
I _D	Drain Current-continuous@ TC=25°C	18	A
P _{tot}	Total Dissipation@TC=25°C	100	W
Tj	Max. Operating Junction Temperature	150	C
T_{stg}	Storage Temperature Range	-55~150	$^{\circ}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.25	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	30	°C/W





	mm	
DIM	MIN	MAX
Α	19.90	20.10
В	15.90	16.10
C	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.10
H	5.90	6.10
J	0.595	0.605
K	22.30	22.50
L	1.90	2.10
N	10.80	11.00
0	4.90	5.10
R	3.75	3.95
S	3.20	3.40
U	9.90	10.10
Υ	4.70	4.90
Z	1.90	2.10

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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =1mA	500			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	2.5	1	3.5	>
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =9A		0.25	0.35	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±30V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V; V _{GS} = 0			500	μ A
Ciss	Input capacitance	X		3300	4950	
Crss	Reverse transfer capacitance	V_{DS} =25V; V_{GS} =0V; f_T =1MHz		80	120	pF
Coss	Output capacitance			340	510	
tr	Rise time			80	120	
ton	Turn-on time	V _{GS} =10V;l _D =18A; V _{DD} =300V;	-	35	55	
tf	Fall time	R _L =10 Ω		120	180	ns
toff	Turn-off time			190	285	

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